

# isc N-Channel MOSFET Transistor

# AOTF290L

### • FEATURES

- Drain Current –I<sub>D</sub>= 72A@ T<sub>C</sub>=25℃
- · Drain Source Voltage-: V<sub>DSS</sub>= 100V(Min)
- Static Drain-Source On-Resistance
- :  $R_{DS(on)} = 4.2m \Omega$  (Max)
- 100% avalanche tested
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION

· Be suitable for synchronous rectification for server and general purpose applications

SYMBOL	PARAMETER	VALUE	VALUE UNIT			
V <sub>DSS</sub>	Drain-Source Voltage 10		V			
V <sub>GS</sub>	Gate-Source Voltage ±20		V			
ID	Drain Current-Continuous	72	A			
I <sub>DM</sub>	Drain Current-Single Pulsed	290	А			
PD	Total Dissipation @Tc=25℃	48	W			
Tj	Max. Operating Junction Temperature	-55~175	Ĉ			
T <sub>stg</sub>	Storage Temperature	-55~175	°C			

### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

# isc website: www.iscsemi.cn

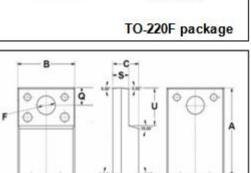
THERMAL CHARACTERISTICS

PARAMETER

Channel-to-case thermal resistance

SYMBOL

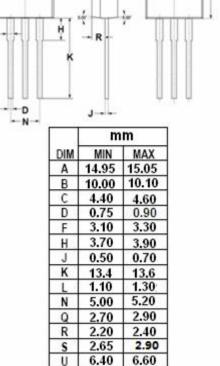
Rth(ch-c)



123

pin 1.Gate 2.Drain

3. Source



1 isc & iscsemi is registered trademark

U

UNIT

°C/W

MAX

3.1



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### ELECTRICAL CHARACTERISTICS

#### $T_{\text{C}}\text{=}25\,^\circ\!\!\!\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID = 250 μ A	100		V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; ID = 250 μ A	2.9	4.1	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 20A V <sub>GS</sub> = 10V; I <sub>D</sub> = 20A;T <sub>J</sub> = 125 °C		4.2 6.1	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}$ = ±20V; $V_{DS}$ = 0V		±100	nA
Idss	Drain-Source Leakage Current	V <sub>DS</sub> = 80V; V <sub>GS</sub> = 0V V <sub>DS</sub> = 80V; V <sub>GS</sub> = 0V;T <sub>J</sub> = 55°C		1 5	μA
V <sub>SD</sub>	Diode forward voltage	Is= 1A; V <sub>GS</sub> = 0V		1	V

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